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# Urchin-Inspired ZnO-TiO<sub>2</sub> Core-Shell as Building Blocks for Dye Sensitized Solar Cells

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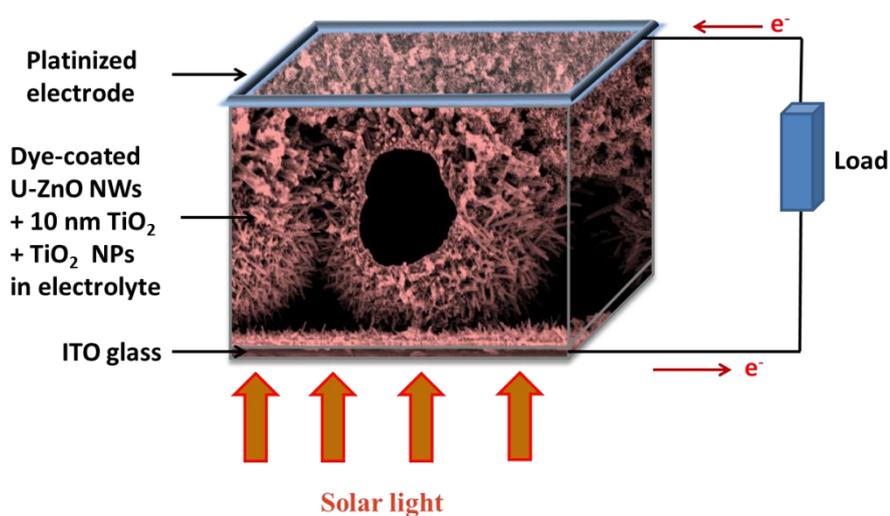
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## ABSTRACT

We applied the core-shell concept to an urchin-inspired ZnO nanowire photoanode building block as a means to increase the electron transport and reduce recombination between nanowire and electrolyte. Dye-sensitized solar cells (DSSCs) were prepared, for the first time, from arrays of urchin-like ZnO nanowire building blocks covered with a thin layer of anatase TiO<sub>2</sub> by atomic layer deposition (ALD). An increase in the cell open-circuit voltage ( $V_{OC}$ ) and

an improvement in the conversion efficiency were observed when the urchin-like ZnO building blocks were coated with 10 nm thick TiO<sub>2</sub> ALD shells in combination with 10 μm thick top layer of TiO<sub>2</sub> nanoparticles of 15.8 nm size. Using urchin-like ZnO nanowires as building blocks can improve the light-scattering and provide a higher surface area with a great control of the nanowire dimensions to increase the dye loading and reduce the electron collection path. The addition of a thin TiO<sub>2</sub> blocking layer decreases the recombination of charges in such a high surface area nanostructure.

#### GRAPHICAL ABSTRACT



#### KEYWORDS

Dye sensitized solar cells, core-shell nanostructures, urchin-like ZnO nanowires, TiO<sub>2</sub>, Atomic Layer Deposition

## INTRODUCTION

The need to find an alternative to oil, and move towards clean and renewable energies, promotes since the last decades the emergence of new technologies. Among the different types of renewable energy, photovoltaic energy, based on the direct processing of the sunlight into electricity, has a significant potential [1]. One of the main objectives in this field of research is to reduce the processing costs of photovoltaic modules, using widely available and abundant materials which can be incorporated into a clean manufacturing processes, in order to create a genuine market competitor to other energy sources (fossil, nuclear, hydro), considered up to today as less costly. The dye-sensitized solar cell (DSSC) has become a promising alternative to commercial solar cells due to their low production cost and ease of fabrication [2-4]. In a DSSC, the photogenerated electrons at the light absorbing dye are injected to the conduction band of a wide band gap metal oxide nanostructure (*i.e.* TiO<sub>2</sub>, ZnO), to be transported towards the current collector. Subsequently, the dye is regenerated by the redox couple of the electrolyte (*i.e.* I/I<sup>3-</sup>) [5]. Conventional DSSCs consist of a mesoporous nanocrystalline TiO<sub>2</sub> film which possess a large surface area but with numerous grain boundaries, which ultimately increases the recombination rates of photogenerated electron-hole pairs and consequently lowers the photovoltaic efficiency [6, 7]. A major condition for electricity generation with a high photovoltaic efficiency is that the electron-hole pairs should not recombine (or very rarely). One goal of this study is suppressing the delicate balance between transport of charges and recombination of electron-hole pairs by using a specific architecture of semiconductor materials to accelerate electron transport and minimize recombination of electron-hole pairs by optimizing the nature, structure and dimensions of the semiconductors.

Alternatively, the use of semiconducting nanowires/nanotubes (e.g., ZnO, TiO<sub>2</sub>, etc.) as the nanostructured photoanode offers several advantages such as a high surface area and a direct

electron transport owing to the lower amount of grain boundaries that both reduces the recombination of charges and increases the collection efficiency [8-10]. In addition, the unique geometry of the nanowires provides an improvement of the optical absorption and light trapping through a wide range of wavelengths, while reducing optical reflection [11].

Among the n-type semiconductor materials with large band gap, ZnO has been widely studied due to its non-toxicity and abundance on Earth [12]. For these reasons, ZnO nanowires are an ideal candidate for a nanostructured photoanode in DSSCs. While the direct electrical pathways to the electrode provided by the ZnO nanowires ensure the rapid collection of carriers generated throughout the device, it turns out that the conversion efficiency is limited by the surface area of the nanowire array [13-15]. These nanostructures have light harvesting efficiencies below 10 %, which can be improved by increasing the nanowire surface area with the control of the dimensions of each individual nanowire as reported in the literature [13, 15]. To tackle this challenge, we previously reported a novel approach to fabricate well-ordered arrays of hollow urchin-like single-crystal ZnO nanowire building blocks with controlled nanowire for photovoltaic applications [8, 16]. They were synthesized by combining the methods of auto-assembly of polystyrene spheres, atomic layer deposition (ALD), and electrodeposition (ECD) of ZnO nanowires. ALD and ECD are low-cost and large scalable process for the synthesis of hollow urchin-like ZnO nanowires. [17] This architecture combined the properties of 1D and 3D materials (higher surface area) and provided better control of the dimensions of the nanowires. The diameters, density and morphology of the nanomaterials were adjusted by tuning the growth parameters during the deposition (ALD and/or ECD), or by modifying the diameter of the PS. The opto-electronic, structural and morphological properties of these nanostructures impact the photovoltaic efficiency.

In this work, similar Urchin-inspired ZnO nanostructures were prepared and used as building blocks for the photoanode to fabricate DSSCs. The effect of the growth conditions on the conversion efficiency of the DSSCs was experimentally evaluated and discussed. Here we show that the recombination of charges in the urchin-inspired ZnO nanowires dye-sensitized cells could be decreased and the conversion efficiency enhanced by coating the urchin-like ZnO nanowire with a conformal TiO<sub>2</sub> shell deposited by ALD. ALD is a unique vapor-phase deposition technique of high quality conformal and homogenous thin films at relatively low temperatures with a precise thickness control. These properties are ideal for surface and interface engineering for next generation solar cells [18-21]. Many studies have described the effects of using insulating or semiconducting thin films of metal oxides as compact and blocking layers to reduce charge recombination at the different interfaces of the nanostructured solar cell. These films coating the transparent current collector (i.e. FTO) and/or the metal oxide nanostructure include Nb<sub>2</sub>O<sub>5</sub>, Al<sub>2</sub>O<sub>3</sub>, MgO, SrTiO<sub>3</sub>, SiO<sub>2</sub>, Y<sub>2</sub>O<sub>3</sub>, ZrO<sub>2</sub>, SnO<sub>2</sub>, and TiO<sub>2</sub> [22-27]. In general, a layer of oxide semiconductor plays an important role by passivating the surface defects of the metal oxide nanostructures, as well as adding an energy barrier that increases the separation between photoinjected electrons and the oxidized redox species in the electrolyte and consequently reduces recombination of charges [10]. These barrier recombination layers have to be thin enough to allow efficient photoelectron injection, and as the thickness decreases, the charge transfer resistance decreases. Therefore, this highlights the need of ALD to properly control the thickness of such layers. An overview of such layers deposited using different techniques can be found in reference [28]. A lower rate of recombination can be translated as a lower dark current ( $J_{\text{dark}}$ ) and a higher open-circuit voltage (and fill factor) of a DSSC according to the general expression of the cell open-circuit voltage ( $V_{\text{OC}}$ ):  $V_{\text{OC}} = nV_{\text{th}} \ln((J_{\text{SC}}/J_{\text{dark}}) + 1)$ , where  $n$  is the diode ideality factor and  $V_{\text{th}}$  is the thermal voltage [29]. In addition to reduce the recombination, an energy barrier shell can

pointedly increase cell  $V_{OC}$  directly if it creates a dipole at the core-shell interface that shifts the band edge of the core upward in energy [25].

Until now, low conversion efficiencies were obtained when using ZnO nanowires [30], ZnO nanotubes [31] or ZnO nanoparticles [3, 32] as building blocks for DSSCs. We describe, for the first time, the ability of a 3D architecture based on urchin-like ZnO nanowires with larger surface area coated with TiO<sub>2</sub> nanostructure to enhance the performance of the DSSCs. Applying the core-shell concept to an urchin-inspired single crystal ZnO nanowire photoanode building block as demonstrated in this work provides a means to increase the electron transport and reduce recombination between nanowire and electrolyte.

## MATERIALS AND METHODS

### 1. Deposition of polystyrene microsphere

A commercially available suspension of polystyrene microsphere (PS) (diameter ~ 5  $\mu\text{m}$ , 4 wt% aqueous dispersion) from Thermo fisher, USA, was used for dip coating transparent Indium doped tin oxide (ITO) deposited on glass (size 1 x 5  $\text{cm}^2$ ) purchased from Kintec Company, Hong Kong. Before making the deposition of spheres on the ITO glass, the substrate was subjected to a specific cleaning technique to remove surface dirt (grease, dust etc.) collected after manufacturing and during the storage. The cleaning method included, first, washing the substrates with commercial soap and hot water (~ 90 °C) followed by rinsing with ultra-purified water. Then the substrates were soaked for 15 minutes in an ultrasonic bath at 70 °C in three different solvents: trichloroethylene, acetone and isopropanol and in between rinsed with ultra-pure water heated to 90 °C. The resulting substrates were dried and stored in plastic boxes to prevent possible contamination prior to deposition. 200  $\mu\text{L}$  of a carboxylate modified PS microsphere suspension was diluted in 150  $\mu\text{L}$  of ethanol and

then dispersed (drop-by-drop using a micro-pipette) onto the surface of deionized water filled into a Petri dish of 5 cm in diameter to self-assemble for about 12 hours. An ITO substrate was exposed under a UV lamp for 10 min to promote the adherence of the PS spheres on the surface of the substrate and then immersed into the suspension. The polystyrene sphere monolayer was transferred onto the ITO substrate surface by slow removal from the solution at an angle of 45° [16]. After complete drying of the PS-covered ITO/glass substrate in furnace at 100 °C for 30 min, the regularly arranged and closely packed spheres were reduced in diameter using an oxygen plasma treatment by fixing the pressure at 0.7 mbar and the power supply at 0.2 A. The size of the polystyrene spheres was very accurately controlled by choosing the appropriate plasma exposure time [6].

## **2. Synthesis of ZnO Urchins**

The ITO covered with PS (ITO/PS) was introduced into a custom made atomic layer deposition (ALD) reactor for deposition of a ZnO thin film covering homogeneously the spheres and the ITO substrate surface [9]. The ZnO<sub>ALD</sub> thin films play two important roles: it is used as a seed layer that controls the growth of the ZnO nanowires, and it renders the surface electrically active to be used as a conductive electrode for electrodeposition. The ZnO<sub>ALD</sub> thin films were deposited using diethylzinc (DEZ) and water (H<sub>2</sub>O). Diethyl Zinc (DEZ) (Zn(CH<sub>2</sub>CH<sub>3</sub>)<sub>2</sub>, 95% purity, CAS: 557-20-0) was purchased from Sigma Aldrich and used as zinc source. The ALD was performed by sequential exposures of DEZ and H<sub>2</sub>O separated by Argon purge at a flow rate of 100 standard cubic centimeters per minute (sccm). The regime for the deposition of ZnO consisted of 0.2 s pulses of DEZ, 40 s of exposure to DEZ, 60 s of Argon purge followed by 2 s pulse of H<sub>2</sub>O, 40 s exposure to H<sub>2</sub>O, and a final 60 s Argon purge [16]. This constituted one cycle. ZnO films with 100 ALD cycles were

deposited on ITO glass substrates for obtaining 20 nm thick layers of ZnO. The temperature was fixed at 80°C. The ITO/PS/ZnO<sub>ALD</sub> ensemble was then used as a working electrode for the electrodeposition of ZnO nanowires by bubbling the oxygen in a three-electrode electrochemical cell. A platinum wire was used as the counter electrode and an Ag/AgCl electrode as the reference electrode. The electrolyte was an aqueous solution saturated by molecular O<sub>2</sub> containing zinc chloride as zinc precursor ( $5 \cdot 10^{-4}$  M) and potassium chloride (0.1M) as salt. The electrodeposition was performed for a period of 2 to 4 hours by fixing the potential (-1 V) versus the reference electrode) using an Autolab VERSASTAT3 potentiostat. The bath temperature was set to 80°C. After electrodeposition, the samples were annealed in air at 450 °C for 1h to ensure the removal of the PS spheres and the enhancement of the ZnO nanowires crystallinity. The above process steps defined the hollow urchin-like ZnO nanowires (U-ZnO NWs) building blocks.

### **3. Atomic Layer Deposition of TiO<sub>2</sub> and Dye-sensitized solar cell Fabrication**

The core-shell concept was realized by transferring the urchin-like ZnO nanowires into a built-in ALD reactor to deposit conformal thin films of TiO<sub>2</sub> as recombination barrier layers with different thicknesses (5, 10, 15, 20, 34 and 42 nm). The deposition of TiO<sub>2</sub> was performed onto the urchin-like ZnO nanowires at a reactor temperature of 60 °C by alternating the precursors of Titanium Tetra-Isopropoxide (TTIP) heated to 90 °C and H<sub>2</sub>O heated to 40 °C. One ALD cycle consisted of a TTIP pulse of 5 s followed by a 10 s exposure, and 60 s purge, followed by a H<sub>2</sub>O pulse of 2 s with 10 s exposure and 60 s purge. For some of the samples, a mesoporous film of TiO<sub>2</sub> anatase nanoparticles (P25 Solaronix) was deposited by doctor blade technique on top of the ZnO/TiO<sub>2</sub> core-shell structures.

The samples were then heated to 450 °C in air for 30 min and then immersed in a solution of 12 mg of Ru dye (N719, Solaronix) diluted in 30 mL of methanol for 12 h. In

order to fabricate the cell, the films were rinsed with ethanol, dried, and sandwiched together to a platinum counter electrode separated by a 60- $\mu\text{m}$ -thick hot-melt film (Solaronix). The internal space of each cell was filled with an iodide electrolyte (AN-50, Solaronix). Cells were immediately tested under simulated sunlight and illuminated through a black cover with an aperture of 0.6  $\text{cm}^2$ .

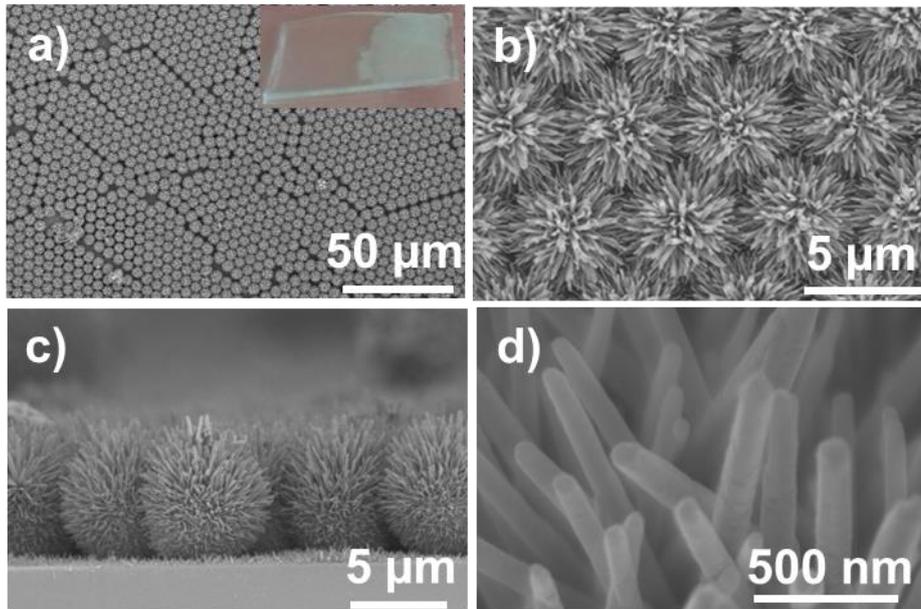
#### 4. Characterization

The morphology of the samples was observed by scanning electron microscopy (SEM, Hitachi S-4800). In order to know the elemental composition of samples, energy dispersive X-ray spectroscopy (EDX) was performed on a JEOL JEM 2200 fs microscope, operated at 200 kV. X-ray diffraction data were obtained on a Bruker D-8 GADDS diffractometer (Co  $K\alpha$ ) to determine the crystalline structures and orientation. Raman spectra were obtained on a Raman microscope (Nova Spectra, ND-MDT) featuring a laser source with a wavelength of 532 nm and a 50 $\times$  objective lens with a numerical aperture of 0.75. Spectra were recorded at a spectral resolution of 2.7  $\text{cm}^{-1}$  with a laser power below 100  $\mu\text{W}$  so that it does not induce phase transformation of  $\text{TiO}_2$ ; the exposure time was 30 s for all the samples.

The reflectivity of the  $\text{TiO}_2$ -hollow U-ZnO NW building blocks and the absorbance of  $\text{TiO}_2$  core-shell U-ZnO NW building blocks were characterized by a spectrophotometer from Perkin Elmer (Lambda 900). The illumination was carried out from the glass/ ITO side. Current–voltage (J–V) measurements were made on the DSSCs under half sun illumination (500  $\text{W}\cdot\text{m}^{-2}$ ). The characteristic parameters of the solar cells, including short-circuit current density ( $J_{\text{sc}}$ ), open-circuit voltage ( $V_{\text{oc}}$ ), fill factor (FF) and overall photoconversion efficiency were extracted from the J–V curves.

## RESULTS AND DISCUSSION

## 1. Synthesis and characterization of U-ZnO NWs

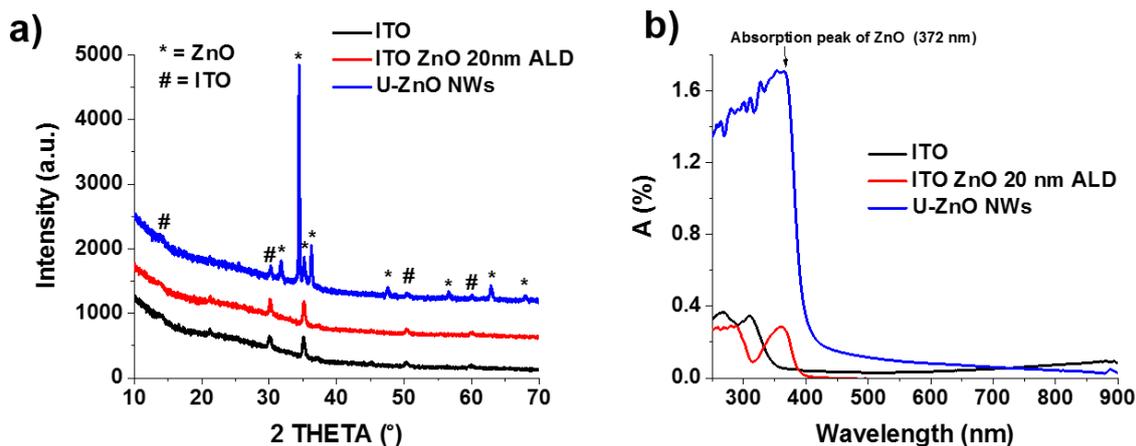


**Figure 1.** SEM images of the U-ZnO NWs: (a) regularly arranged urchin-like ZnO nanowires. The inset shows a macroscopic view of the deposition. (b) Higher resolution of U-ZnO NWs after 25 min of PS plasma etching treatment. (c) longitudinal cross sections showing the growth of ZnO nanowires on the PS and in the gap between them. (d) views of individual U-ZnO NWs grown on the 20 nm thick ALD ZnO coated PS spheres after plasma etching treatment of 25 min.

To obtain the unique architecture of U-ZnO NWs, several steps were used, such as: (i) deposition of an ordered monolayer of PS spheres by dip coating onto an indium doped tin oxide (ITO) glass substrate, (ii) reduction of the size of the spheres by plasma etching treatment, (iii) deposition of a uniform conformal thin layer of ZnO (~ 20 nm) by atomic layer deposition (100 cycles) which renders the surface covered by PS spheres electrically active for subsequent electrodeposition. In addition, this thin ALD ZnO seed layer serves as a compact recombination barrier layer to prevent backflow of electrons and avoid short-circuits between the ITO glass electrode and the electrolyte [33], (iv) electrodeposition of the ZnO

nanowires onto the ITO/PS/ZnO<sub>ALD</sub> [34, 35], and (v) removal of polystyrene spheres by annealing at 450 °C for 1h.

The resulting organized arrays of U-ZnO NWs are deposited on the entire surface of the samples as presented by SEM image in Figure 1a. The inset is a macroscopic view of the sample which shows the uniformity of the deposition. By increasing the time of the plasma etching treatment, it is possible to control the spacing and the overall size of the urchin structures. The etching of PS spheres monolayers was performed with 25 min or with 30 min of plasma (Figure S1a and b). After 25 min of treatment, the size of the spheres decreased from 5 μm to 4 μm leaving 1 μm spacing between the spheres whereas after longer treatment time (30 min), the size of the spheres decreased from 5 μm to 3.5 μm leaving 1.5 μm spacing between the spheres (Figure S1a and b). The SEM images (Figure 1a - d) present the resulting ordered urchin-like structures obtained after 25 min of treatment. The time of etching was optimized in order to have a large fraction of the U-ZnO NWs surface exposed to the incident light. The ZnO NWs are characterized by 948 nm long (Figure 1c) and a diameter of 57 nm (Figure 1d) when the thickness of the ZnO ALD layer is 20 nm. The density of the ZnO nanowires is 5260 NWs/urchin. The overall active surface area of the urchin-like ZnO NWs is 42.25 cm<sup>2</sup> compared to 17.8 cm<sup>2</sup> for the ZnO NWs on a flat substrate (Figure S6 in the Supporting Information). The growth of the nanowires between the urchin nanostructures was also observed (Figure 1c), which also participates to increase the overall surface area.



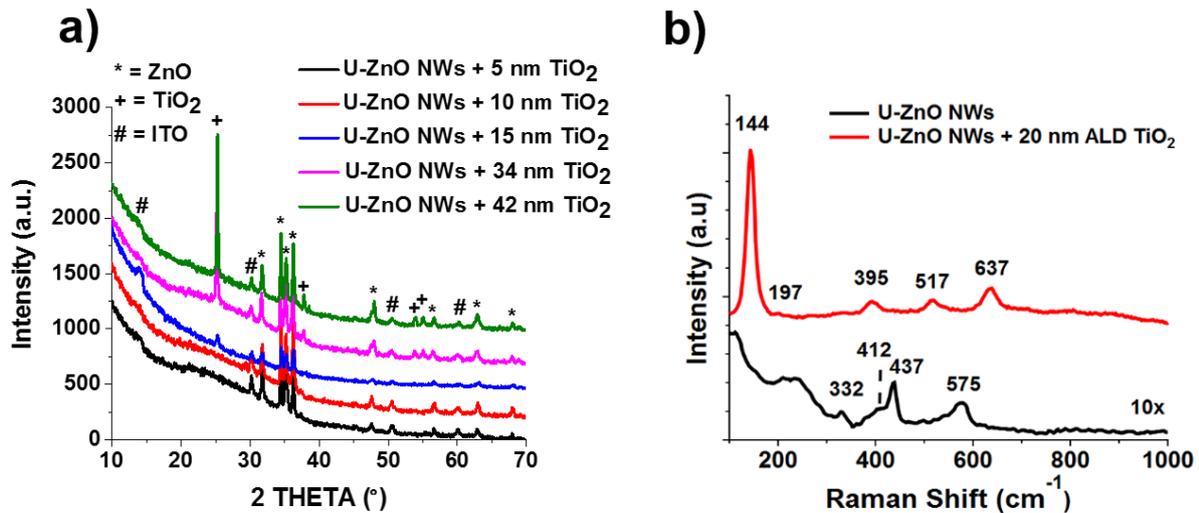
**Figure 2.** a) X-ray diffractograms and b) Absorption spectra of ZnO 20 nm ALD layer on a flat ITO glass substrate and U-ZnO NWs.

EDX analysis confirmed the presence of ZnO as indicated in Table S1. The X-ray diffraction spectrum of the U-ZnO NWs presented in Figure 2a shows the characteristic peaks of the ZnO wurtzite structure. The main orientations of the ZnO NWs are (100) at 34.4°, (002) at 35.2°, and (101) at 36.3° (Figure 2a).

In order to study the influence of U-ZnO NWs on the light scattering, the spectral dependence of the absorption of the samples was measured (Figure 2b). For all analyzed samples based on ZnO, the spectra show UV absorbance edge close to 375 nm (3.3 eV), which corresponds to the band gap energy of ZnO. No absorbance was shown for bare ITO glass sample. The presence of higher absorbance values is due to the presence of higher quantity of ZnO. Especially, the formation of urchins increases significantly the absorption by 30% at 372 nm which supports the stronger advantage of using the high surface area U-ZnO NWs to enhance the light scattering.

## 2. U-ZnO-TiO<sub>2</sub> core-shell nanostructures

### 2. 1. Synthesis of U-ZnO-TiO<sub>2</sub>



**Figure 3.** a) X-ray diffraction pattern of U-ZnO NWs on ITO glass substrates covered with different thicknesses of TiO<sub>2</sub> layer and b) Raman spectra of U-ZnO NWs and U-ZnO NWs/TiO<sub>2</sub> shell.

A uniform conformal and amorphous thin layer of TiO<sub>2</sub> with different thicknesses (5 nm, 10 nm, 15 nm, 20 nm, 34 nm, 42 nm) was deposited by ALD at 60 °C with a growth rate of 0.056 nm/cycle (measured on Si substrates). The samples were then annealed at 450 °C in air for 30 min in order to obtain the anatase phase. The X-ray diffraction (Figure 3a) points out a peak at 25° characteristic of the anatase phase (101) of TiO<sub>2</sub> for the samples based on U-ZnO NWs covered with different thicknesses of TiO<sub>2</sub> ALD layer. Reasonably, the anatase peak becomes more intense when the thickness of the TiO<sub>2</sub> layer increases. The average grain size, calculated from the (101) peak of anatase TiO<sub>2</sub> using the Scherrer formula, was 33.0 nm, 50.5 nm and 65.7 nm for the U-ZnO NWs/ TiO<sub>2</sub> ensemble with a thickness of TiO<sub>2</sub> layer of 15 nm, 34 nm and 42 nm, respectively. The X-ray diffraction spectrum shows also the peaks characteristic of ZnO wurtzite and ITO deposited on the glass substrates (Figure 3a). The anatase phase of TiO<sub>2</sub> was also evidenced by Raman showing the characteristic peaks at 144 cm<sup>-1</sup>, 197 cm<sup>-1</sup>, 396 cm<sup>-1</sup>, 517 cm<sup>-1</sup> and 637 cm<sup>-1</sup> (Figure 3b) for the sample based on U-ZnO

NWs / TiO<sub>2</sub> 20 nm layer ensemble. In the case of the reference sample based on U-ZnO NWs without TiO<sub>2</sub>, only peaks of ZnO were observed.

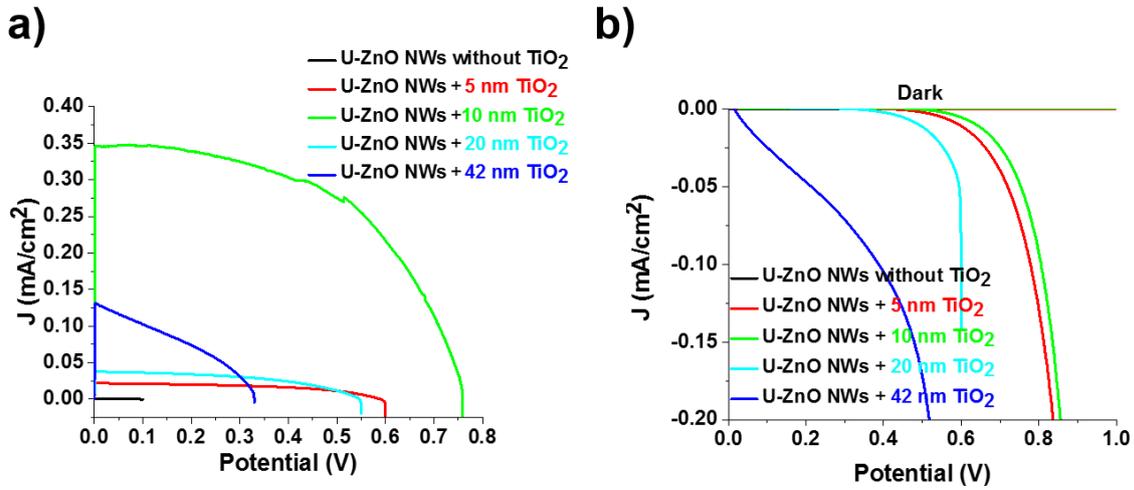
## 2. 2. Characterization of U-ZnO-TiO<sub>2</sub>

The spectral dependence of the transmittance of the samples was studied before (Fig. S3a in the Supporting Information) and after dye loading and subsequent illumination (Fig. S3b), in order to determine the effect of the thickness of the TiO<sub>2</sub> shell on light scattering and dye loading. A small decrease of the transmittance from 70% to 55% was observed for the sample U-ZnO NWs/ TiO<sub>2</sub> layer when increasing the thickness of the TiO<sub>2</sub> layer (Figure S3a). The reference sample based on U-ZnO NWs without TiO<sub>2</sub> has the highest transmittance. The decrease of the transmittance can be explained by the fact that the thick layer of TiO<sub>2</sub> (from 20 nm to 42 nm) absorbs photons and reduces light scattering to the ZnO. This hypothesis will be analyzed later with the study of the J-V curves of the samples.

The spectral dependence of the transmittance of the samples was also measured after dye loading and illumination, as shown in Figure S3b. An increase of absorption in the wavelength range of the excitation of the TiO<sub>2</sub> is noticed when increasing the thickness of TiO<sub>2</sub> layer (34 nm and 42 nm) as a consequence of the higher amount of dye loading (Figure S3b) [36].

The spectral dependence of the optical reflectance of the samples based on U-ZnO NWs with various thickness of TiO<sub>2</sub> shell was also studied (Figure S4 in the Supporting Information). By increasing the thickness of the TiO<sub>2</sub> layer deposited on the U-ZnO NWs, the maximum of the total reflectance (at  $\lambda = 430$  nm) increases from 20% to 35% for 5 to 20 nm TiO<sub>2</sub> thickness, respectively, along with a decrease of the reflectance over the whole wavelength range (Figure S4).

### 2. 3. Solar cell performance of core-shell U-ZnO-TiO<sub>2</sub>



**Figure 4.**  $J$ - $V$  data for DSSC samples based on U-ZnO NWs-TiO<sub>2</sub> core-shell cells with different thicknesses of TiO<sub>2</sub> shell. Each cell was sensitized in dye solution for 12 h. (a) Power plots under 500 Wm<sup>-2</sup> simulated sunlight of U-ZnO NWs coated with TiO<sub>2</sub> of different thicknesses and (b) dark.

The effect of the thickness of TiO<sub>2</sub> on the light scattering has been discussed. The photovoltaic efficiencies were studied by analyzing the  $J$ - $V$  curves obtained for the DSSC samples based on ZnO/ TiO<sub>2</sub> core-shell with various TiO<sub>2</sub> shell (Figure 4). Current-voltage ( $J$ - $V$ ) measurements on the DSSCs were performed under full sun illumination, half sun illumination (500 Wm<sup>-2</sup>) and dark. The characteristic parameters of the solar cells, including short-circuit current density ( $J_{sc}$ ), open-circuit voltage ( $V_{oc}$ ), fill factor (FF) and overall photoconversion efficiency ( $\mu$  (%)) were extracted from the  $J$ - $V$  curves.

Figure 4a presents the  $J$ - $V$  curves for the samples of U-ZnO NWs/ TiO<sub>2</sub> core shell under 500 Wm<sup>-2</sup> coated with different thicknesses of TiO<sub>2</sub> and sensitized in Ru dye for 12 h. The plots also include uncoated U-ZnO NWs cells sensitized in Ru dye for 12 h as a reference cell. The addition of a 10 nm layer of TiO<sub>2</sub> to the U-ZnO NWs cells results in a working cell with an overall efficiency increase from 0 to 0.28%, (the fill factor (FF) jumps from 0.04 to

0.55 (a 90% improvement), and the  $J_{SC}$  jumps from 0 to 0.34 (Figure 4a and table 1). Thus, an improvement in cell efficiency was observed after adding a 10 nm layer of  $TiO_2$  (Figure 4a). For  $TiO_2$  shells thicker than 10 nm (20 nm-42 nm), the  $V_{OC}$  decreases by about 430 mV from 0.76 V to 0.33 V and the FF decreases from 0.55 to 0.34. For  $J_{SC}$ , the current falls from 0.34 to 0.13 (table 1). The plots in Figure 4b show the dark current  $J_{dark}$  of the DSSC cells. The improvement of the  $V_{oc}$  for the thinner  $TiO_2$  coatings suggests a reduction in charge recombination compared to the thicker coatings. Thicker coatings lead to slower charge transport and shorter electron lifetimes resulting in more recombination of charges, evidence by the higher dark currents. This has been reported to be caused by the positive shift of the conduction band of  $TiO_2$  as the thickness increases [36].

Thus, the thickness of  $TiO_2$  layer has a significant influence on the cell efficiency of the device. The  $TiO_2$  blocking layer has to be sufficiently thin to allow electron injection to the ZnO, but with a high surface coverage of the nanostructure and thick enough to prevent the back reaction of electrons. The cell efficiency has almost tripled by only increasing the thickness of  $TiO_2$  layer from 5 nm to 10 nm while the  $V_{OC}$  and FF increase slightly from 0.6 V to 0.76 V and from 0.5 to 0.55, respectively (Figure 4a and table 1).

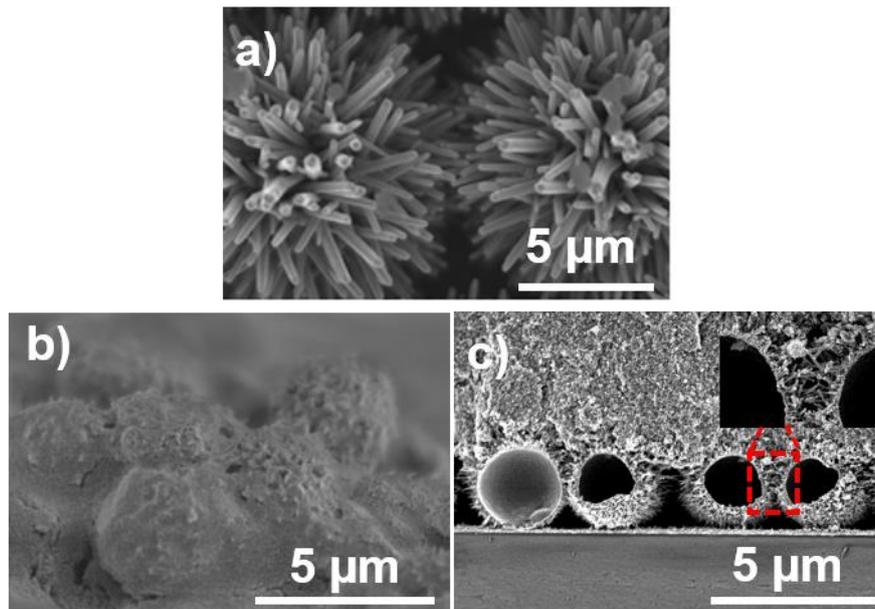
**Table 1.** Dependence of  $V_{OC}$ , FF,  $J_{dark}$ ,  $J_{SC}$ , and efficiency with the thickness of  $TiO_2$  layer.

<b>Samples</b> <b>(U-ZnO NWs/ <math>TiO_2</math> ALD layer)</b>	<b><math>V_{OC}</math></b> <b>(V)</b>	<b>FF</b> <b>(mV)</b>	<b><math>J_{SC}</math></b> <b>(mA cm<sup>-2</sup>)</b>	<b>Efficiency</b> <b>(%)</b>
<b>0 nm <math>TiO_2</math></b>	0.10	0.04	0	<b>0</b>
<b>5 nm <math>TiO_2</math></b>	0.60	0.50	0.02	<b>0.01</b>
<b>10 nm <math>TiO_2</math></b>	0.76	0.55	0.34	<b>0.28</b>

<b>20 nm TiO<sub>2</sub></b>	0.55	0.47	0.04	<b>0.02</b>
<b>42 nm TiO<sub>2</sub></b>	0.33	0.34	0.13	<b>0.03</b>

### 3. Hybrid structure of nanoparticles and urchins

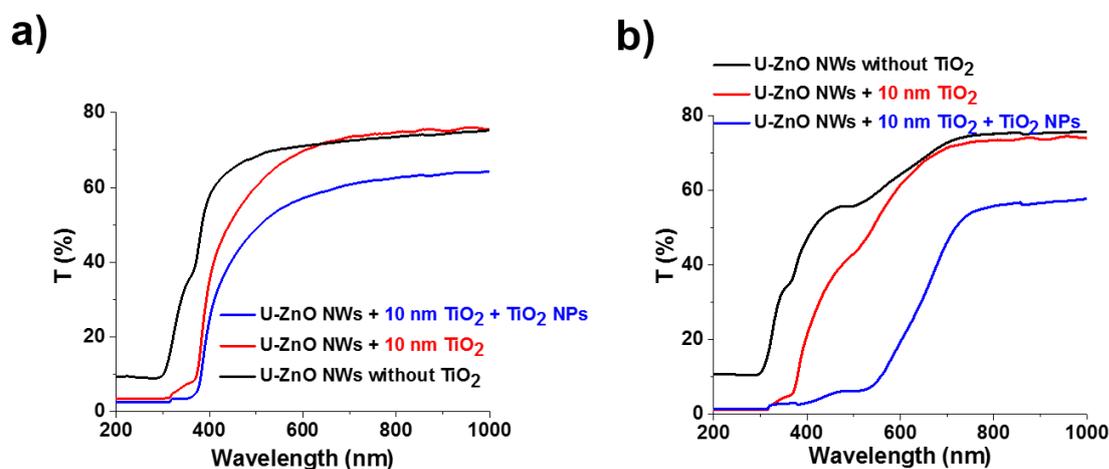
#### 3.1. Synthesis and characterization of TiO<sub>2</sub> nanoparticle on core-shell U-ZnO-TiO<sub>2</sub>



**Figure 5.** SEM images of urchin-inspired ZnO-TiO<sub>2</sub> core-shell and TiO<sub>2</sub> nanoparticle cells. (a) growth of U-ZnO NWs on 20 nm of ZnO<sub>ALD</sub> seed layer deposited on PS spheres treated with 25 min of PE treatment; The urchins based ZnO NWs were covered with 10 nm TiO<sub>2</sub> anatase (b) U-ZnO NWs / TiO<sub>2</sub> 10 nm layer / TiO<sub>2</sub> NPs ensemble; and (c) inset shows the presence of TiO<sub>2</sub> NPs on the ZnO NWs.

A mesoporous film (10 μm) of anatase TiO<sub>2</sub> nanoparticles (TiO<sub>2</sub> NPs) was deposited on the ZnO / TiO<sub>2</sub> 10 nm layer ensemble in order to further increase the surface area (Fig. 5b and c). The commercial TiO<sub>2</sub> nanoparticles provide a surface area of ~ 100 m<sup>2</sup>/g (after firing) and a pore size of 15-20 nm. The overall surface area obtained for the urchins-based ZnO NWs coated with TiO<sub>2</sub> NPs is ~ 113.76 m<sup>2</sup>/g. Figure 5a presents the urchins based ZnO NWs

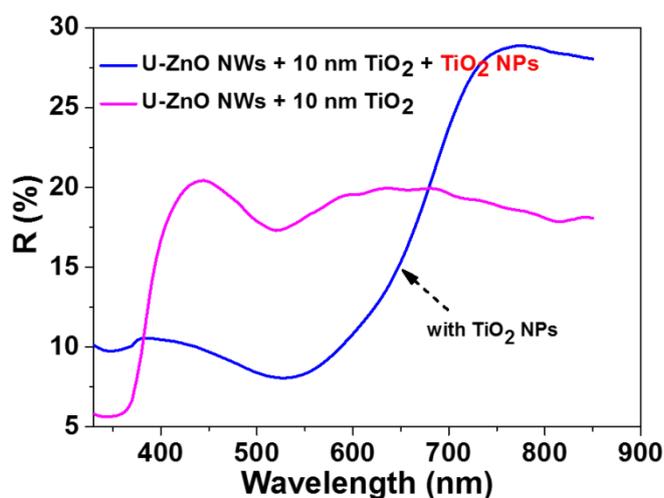
covered with 10 nm TiO<sub>2</sub> anatase without the presence of TiO<sub>2</sub> NPs. Figure 5c shows that the mesoporous TiO<sub>2</sub> film does not infiltrate in between the urchins but rather is supported by them.



**Figure 6.** Transmittance spectra of the DSSC based on U-ZnO NWs / TiO<sub>2</sub> 10 nm layer core-shell and U-ZnO NWs / TiO<sub>2</sub> 10 nm layer / TiO<sub>2</sub> NPs cells (a) before and (b) after illumination.

The influence of the mesoporous film (10 μm) of TiO<sub>2</sub> nanoparticles (TiO<sub>2</sub> NPs) on the ZnO / TiO<sub>2</sub> 10 nm layer ensemble was studied to determine the spectral dependence of the transmittance of the samples before (Figure 6a) and after illumination (Figure 6b).

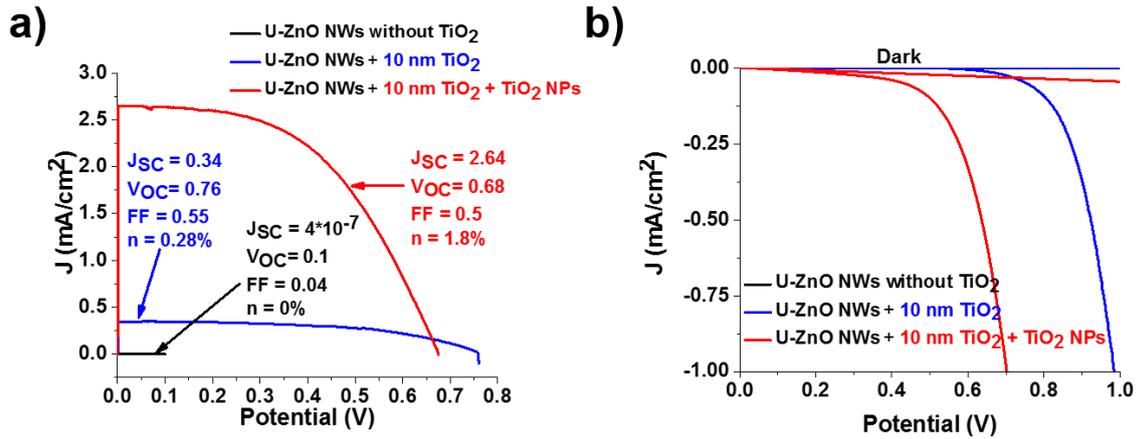
For U-ZnO NWs / TiO<sub>2</sub> 10 nm layer / TiO<sub>2</sub> NPs, the transmittance decreases from 75% to 60% after adding TiO<sub>2</sub> nanoparticles as compared with U-ZnO NWs / TiO<sub>2</sub> 10 nm layer without TiO<sub>2</sub> nanoparticles, owing to the presence of a thick mesoporous layer of TiO<sub>2</sub> nanoparticles with larger surface area and consequently a larger amount of dye adsorbed as shown in Figure 6b. The reference sample based on U-ZnO NWs without TiO<sub>2</sub> has the highest transmittance. Furthermore, adding TiO<sub>2</sub> nanoparticles on the U-ZnO NWs covered with 10 nm layer of TiO<sub>2</sub> can enhance even more the surface area and dye loading and consequently increase the conversion efficiency of the DSSC.



**Figure 7.** Reflectance spectra of the DSSC based on U-ZnO NWs/ TiO<sub>2</sub> 10 nm layer core-shell after illumination as a function of the addition of TiO<sub>2</sub> NPs.

The spectral dependence of the optical reflectance of the U-ZnO NWs / TiO<sub>2</sub> 10 nm layer core-shell and U-ZnO NWs / TiO<sub>2</sub> 10 nm layer / TiO<sub>2</sub> NPs cells was also studied (Figure 7). In our three-dimensional architecture based on U-ZnO NWs, the increase of the reflectivity covers a large wavelength range (400-800 nm). This can be explained due to the fact that nanowires from ZnO urchins are exposed to the incident light from all angles thanks to the 3D-architecture. As shown and explained in the transmittance spectra of the DSSC based on ZnO/ TiO<sub>2</sub> core-shell after illumination, a broadening in the wavelength range of the reflectance was noticed after adding TiO<sub>2</sub> nanoparticles to the DSSC based on U-ZnO NWs/ TiO<sub>2</sub> layer due to the thick layer of TiO<sub>2</sub> nanoparticles (10 μm). The total reflectance (at λ= 600 nm) increased from 16% to 28% for 10 μm thickness of TiO<sub>2</sub> nanoparticles.

### 3.2. Solar cell performance of hybrid nanoparticle core shell structure



**Figure 8.**  $J$ - $V$  data for DSSC samples based on U-ZnO NWs/ TiO<sub>2</sub> (10 nm layer) core-shell cells with and without the addition of TiO<sub>2</sub> nanoparticles. Each cell was sensitized in dye solution for 12 h. Power plots (a) under 500 Wm<sup>-2</sup> simulated sunlight and (b) dark. The short-circuit current density ( $J_{sc}$ ), the open-circuit voltage ( $V_{oc}$ ), the fill factor (FF) and the overall photoconversion efficiency ( $\mu$  (%)) are specified for each device.

A considerable improvement of the characteristic parameters of the solar cell based on U-ZnO NWs/ TiO<sub>2</sub> (10 nm layer) was observed after adding TiO<sub>2</sub> nanoparticles (U-ZnO NWs/ TiO<sub>2</sub> (10 nm layer)/ TiO<sub>2</sub> NPs): the cell efficiency improved from 0.28% to 1.8% and the  $J_{SC}$  increased from 0.34% to 2.64%. The  $V_{OC}$  decreases slightly from 0.76 V to 0.68 V, while the FF remains almost the same value (0.5) (Figure 8a and table 2). The improvement in cell efficiency using the U-ZnO NWs/ TiO<sub>2</sub> (10 nm layer) in combination with the TiO<sub>2</sub> nanoparticles is mainly due to the increase in surface area and thus the dye loading. However, low electron transport and recombination mechanisms due to the grain boundaries and surface defects are still present in the mesoporous TiO<sub>2</sub> NP film, as observed from the high dark currents (Figure 8b). This effect can be further improved by depositing a thin blocking layer onto the NPs, as reported elsewhere[37]. It has to be noted that the photogenerated electrons from the adsorbed dye at the mesoporous TiO<sub>2</sub> layer are transported through the TiO<sub>2</sub> coated

U-ZnO NWs, this film is only in contact with the urchins and not the substrate as observed from Figure 5c.

We also fabricated a DSSC based only on a 10  $\mu\text{m}$  mesoporous film of  $\text{TiO}_2$  NPs using the same fabrication method as for the U-ZnO NWs/  $\text{TiO}_2$  (10 nm layer)/  $\text{TiO}_2$  NPs as a benchmark to compare to the cells based on a hybrid structure of urchins and  $\text{TiO}_2$  nanoparticles. The overall efficiency of such DSSC was found to be 1.5% (see Table 2). This is rather low compared to what is reported in literature, but nevertheless it serves as a comparison to show the potential of the U-ZnO NWs as conductive nanoscaffold.

Thereby, the highest characteristic parameters were obtained for the DSSC based on U-ZnO NWs/  $\text{TiO}_2$  (10 nm layer)/  $\text{TiO}_2$  NPs ( $J_{\text{SC}} = 2.64 \text{ mA/cm}^2$ ,  $V_{\text{OC}} = 0.68 \text{ V}$ ,  $\text{FF} = 0.5$ ,  $\mu = 1.8\%$ ,  $J_{\text{dark}} = 4.6 \text{ mA/cm}^2$ ).

**Table 2.** Dependence of  $V_{\text{OC}}$ ,  $\text{FF}$ ,  $J_{\text{dark}}$ ,  $J_{\text{SC}}$ , and efficiency with the thickness of  $\text{TiO}_2$  layer in the presence of  $\text{TiO}_2$  NPs.

<b>Samples</b>	<b><math>V_{\text{OC}}</math></b>	<b>FF</b>	<b><math>J_{\text{SC}}</math></b>	<b>Efficiency</b>
<b>(U-ZnO NWs/ <math>\text{TiO}_2</math> ALD layer)</b>	<b>(V)</b>	<b>(mV)</b>	<b>(<math>\text{mA cm}^{-2}</math>)</b>	<b>(%)</b>
<b>5 nm <math>\text{TiO}_2</math></b>	0.6	0.5	0.02	<b>0.01</b>
<b>5 nm <math>\text{TiO}_2</math> + <math>\text{TiO}_2</math> NPs (10 <math>\mu\text{m}</math>)</b>	0.61	0.49	1.03	<b>0.62</b>
<b>10 nm <math>\text{TiO}_2</math></b>	0.76	0.55	0.34	<b>0.28</b>
<b>10 nm <math>\text{TiO}_2</math> + <math>\text{TiO}_2</math> NPs (10 <math>\mu\text{m}</math>)</b>	0.68	0.5	2.64	<b>1.8</b>
<b><math>\text{TiO}_2</math> NPs (10 <math>\mu\text{m}</math>)</b>	0.64	0.59	2.03	<b>1.5</b>

#### 4. Discussion

Table 1 summarizes the  $V_{OC}$ , FF,  $J_{SC}$ , and efficiency as a function of the thickness of the  $TiO_2$  layer. The  $V_{OC}$  and FF increase to 0.76 V and 0.55, respectively, after the deposition of a 10 nm layer of  $TiO_2$ , which then gradually decrease by increasing the thickness of the  $TiO_2$  layer (20 nm and 42 nm). Increasing the thickness of the  $TiO_2$  layer reduces the light scattering to the ZnO and decreases the electron injection to the ZnO, whereas the thin  $TiO_2$  coatings reduce the recombination of charges at the interface while still allowing electron injection to the ZnO, as observed from the low dark currents.

After adding  $TiO_2$  nanoparticles to the U-ZnO NWs – 10 nm  $TiO_2$  layer ensemble, the surface area increases and consequently the dye loading, therefore the overall efficiency increases up to 1.8 %, regardless of the slight decrease in the  $V_{OC}$  (from 0.76 to 0.68 V) (Table 2). The  $TiO_2$  nanoparticles are still subjected to recombination mechanisms and thus the significant reduction of the  $V_{oc}$  onset from dark measurements (Figure 8b). These data clearly show that thin  $TiO_2$  shells enhance  $V_{OC}$  and fill factor by reducing the recombination of electron hole pairs at the oxide-electrolyte interface, which strongly depend on the thickness of this  $TiO_2$  layer (Table 1), highlighting once more the need of ALD to precisely control the thickness of the film.

Hence, these results show an improvement of the conversion efficiency to 1.8% compared to 0.8% and 0.7% for ZnO nanowires [14, 30, 38], 0.6% for ZnO nanoparticles [3, 32] and even lower efficiency (0.29%) [31] for ZnO nanotubes through the specific geometry of ZnO urchins nanowire arrays, and 1.3% for urchins inspired ZnO nanowires [8] by including a  $TiO_2$  recombination barrier layer. The ALD  $TiO_2$  layer reduces the recombination rate of photo injected electrons in the U-ZnO structure that otherwise would have recombined with either a surface defect or the electrolyte in contact with the U-ZnO structure. The

combination of the coated U-ZnO with a mesoporous film of TiO<sub>2</sub> nanoparticles increased the amount of adsorbed dye, increasing the photocurrent and therefore improved the characteristic parameters of the solar cell. Although, our actual cell efficiencies are still lower than standard nanoparticle-based solar cells, we demonstrated the use of U-ZnO coated with ALD TiO<sub>2</sub> as a conductive scaffold, as the majority of the current was transported through the urchins. We believe that there is a possibility to further improve the conversion efficiency by further optimization of the total surface area of the U-ZnO NWs in addition to the mesoporous TiO<sub>2</sub> film or by using a film of perovskite absorber as the light-harvesting active layer [39, 40].

## CONCLUSION

Core-shell DSSC cells were fabricated and characterized. The unique 3D architecture of urchin-like ZnO nanowire arrays have increased the absorbed amount of light due to its larger surface area compared to ZnO nanowires. The urchin-like ZnO nanowires were prepared by a low cost technique electrodeposition of ZnO nanowires on polystyrene spheres coated with 20 nm of ZnO by ALD. The resulting U-ZnO nanostructures were coated with conformal and amorphous TiO<sub>2</sub> shells by ALD which were annealed at 450 °C in order to obtain the anatase phase. These nanostructures were then sensitized with a solution of Ru dye (N719). Coating the U-ZnO NWs with 5-10 nm of anatase TiO<sub>2</sub> has reduced the recombination of charges, improved the J<sub>SC</sub>, V<sub>OC</sub>, FF and consequently the overall conversion efficiency. For TiO<sub>2</sub> shells thicker than 10 nm (20 nm - 42 nm), the transmittance decreases due to a larger absorption of photons from TiO<sub>2</sub>, reducing light scattering to the ZnO. Even though thicker TiO<sub>2</sub> layers can adsorb more dye, they lead to lower charge transport resulting in more recombination of charges, as observed from the higher dark currents. A considerable improvement of the characteristic parameters of the solar cell was observed after adding a mesoporous film of TiO<sub>2</sub> nanoparticles. Adding TiO<sub>2</sub> nanoparticles on the TiO<sub>2</sub> coated U-ZnO NWs can increase

further the surface area and consequently increase the conversion efficiency of the DSSC, most likely due to the larger dye loading. Nevertheless, the large surface area of the nanoparticles, grain boundaries and surface defects still lead to recombination of charges, which limits the full potential of the cell, which can be improved by depositing another thin blocking layer to the NPs. Ultimately, it is worth mentioning that the photogenerated current was transported in its majority through the U-ZnO, which evidences the high conductivity of such nanostructures, and further optimization may improve the overall conversion efficiency.

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#### AUTHORS' CONTRIBUTION

Chantal Karam, Ziad Herro, Nadine Abboud, Sophie Tingry did the electrodeposition and characterizations of Urchin-Inspired ZnO Nanowires; Mikhael Bechelany and Philippe Miele did experiments on Atomic layer deposition of ZnO and analyzed the results; Chantal Karam, Carlos Guerra-Nuñez, Roland Habchi, Antonio Khoury, did the physico-chemical characterization of the obtained materials and analyzed the obtained results; Chantal Karam, Ivo Utke and Carlos Guerra-Nuñez did experiments on Atomic layer deposition of TiO<sub>2</sub> and Dye Sensitized Solar Cells; Ivo Utke and Mikhael Bechelany designed the works and write the manuscript.

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